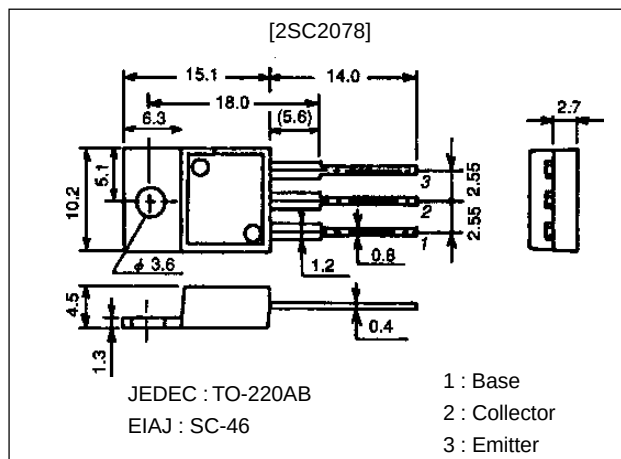


**2SC2078****27MHz RF Power Amplifier Applications****Package Dimensions**

unit:mm

2010C

**Specifications****Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$**

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		80	V
Collector-to-Emitter Voltage	V_{CER}	$R_{BE}=150\Omega$	75	V
Emitter-to-Base Voltage	V_{EBO}		5	V
Collector Current	I_C		3	A
Collector Current (Pulse)	I_{CP}		5	A
Collector Dissipation	P_C		1.2	W
		$T_c=50^\circ\text{C}$	10	W
Junction Temperature	T_J		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=40\text{V}, I_E=0$			10	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=4\text{V}, I_C=0$			10	μA
DC Current Gain	h_{FE}	$V_{CE}=5\text{V}, I_C=0.5\text{A}$	25*		200*	
Gain-Bandwidth Product	f_T	$V_{CE}=10\text{V}, I_C=0.1\text{A}$	100	150		MHz
Output Capacitance	C_{ob}	$V_{CB}=10\text{V}, f=1\text{MHz}$		45	60	pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=1\text{A}, I_B=0.1\text{A}$		0.15	0.6	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=1\text{A}, I_B=0.1\text{A}$		0.9	1.2	V

* : The 2SC2078 are classified by 0.5A h_{FE} as follows :

25	B	50	40	C	80	60	D	120	100	E	200
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■ Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.

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SANYO Electric Co.,Ltd. Semiconductor Business Headquarters

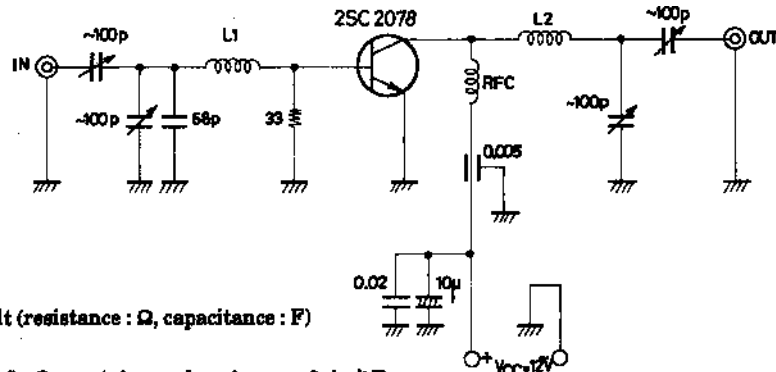
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N1098HA (KT)/D251MH/4147KI/3145KI/2274KI No.462-1/4

2SC2078

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Base Saturation Voltage	$V_{(BR)CBO}$	$I_C=100\mu A, I_B=0$	80			V
Collector-to-Emitter Saturation Voltage	$V_{(BR)CER}$	$I_C=1mA, R_{BE}=150\Omega$	75			V
Emitter-to-Base Saturation Voltage	$V_{(BR)EBO}$	$I_E=100\mu A, I_C=0$	5			V
[At specified test circuit]						
Output Power	P_O	$V_{CC}=12V, f=27MHz, P_i=0.2W$	4.0			W
Power Efficiency	η		60			%

27MHz Output Power Test Circuit



Coil data L1: 0.3mm tinned wire, 9 ϕ 4T

L2: 0.6mm tinned wire, 9 ϕ 4T

RFC 2.2 μ H

